

ISPSD 97: 1997 IEEE International Symposium On Power Semiconductor Devices And ICs, May 26-29, 1997, Weimar, Germany

by International Symposium on Power Semiconductor Devices & ICs ; L Lorenz; Institute of Electrical and Electronics Engineers; Verband Deutscher Elektrotechniker

ISPSD 97: 1997 IEEE International Symposium on Power . 30 Jul 2015 . DOI: 10.1109/PESC.2008.4591961
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